CMOS LSI

No. 3122A

SANYO

LC66P308

4-bit Microcontroller with Built-in PROM

OVERVIEW

The LC66P308 is a 4-bit microcontroller with a built-in 8 Kbyte PROM. It is compatible with the LC663XX series mask ROM devices, making it ideal for prototyping and software development and testing.
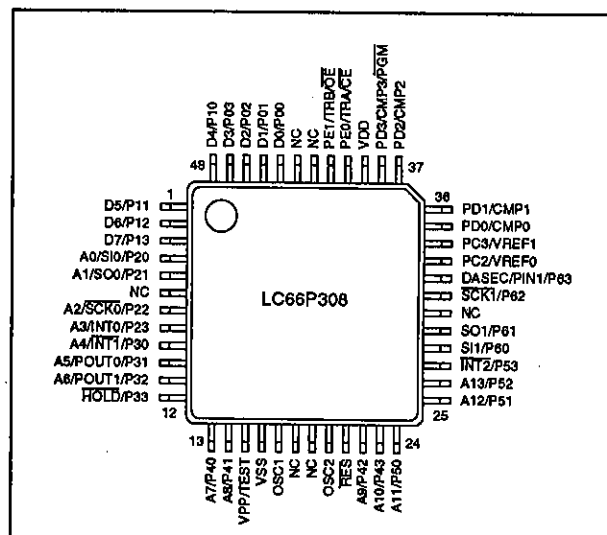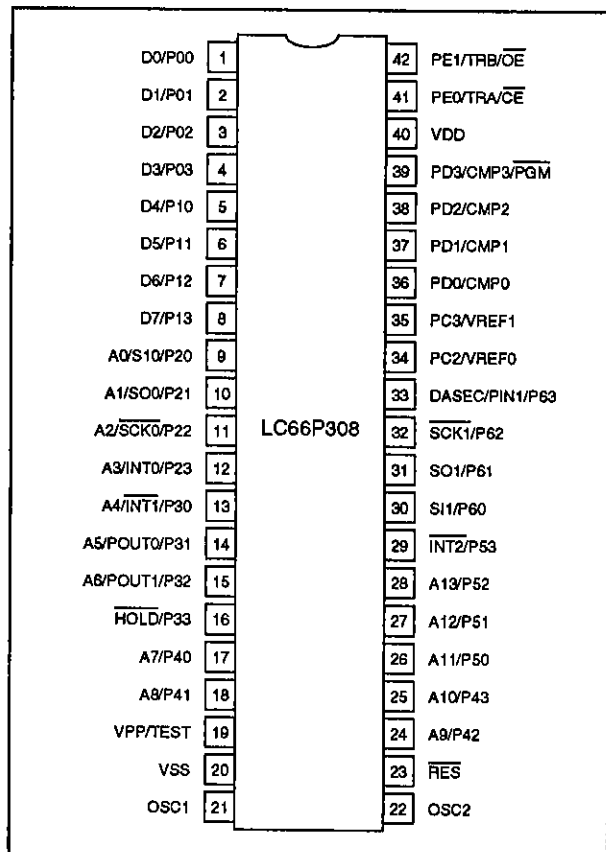
The LC66P308 features 33 user-defined options comprising output configuration, output level after reset, watchdog timer and oscillator configuration options. The output configuration options are open-drain, open-drain with pull-up, and CMOS. The oscillator options are ceramic resonator, RC oscillator and external clock.

The LC66P308 operates from a 5 V supply and is available in 42-pin DIPs and 48-pin QIPs.

FEATURES

* 33 user-defined options including port output configuration, output level after reset and watchdog timer options
* Ceramic resonator, RC oscillator or external clock option
* 8 Kbyte PROM (0000H to 2007H user addressable)
* Compatible with the LC663XX series mask ROM devices
* 0.92 to 10.0 µs instruction cycle time
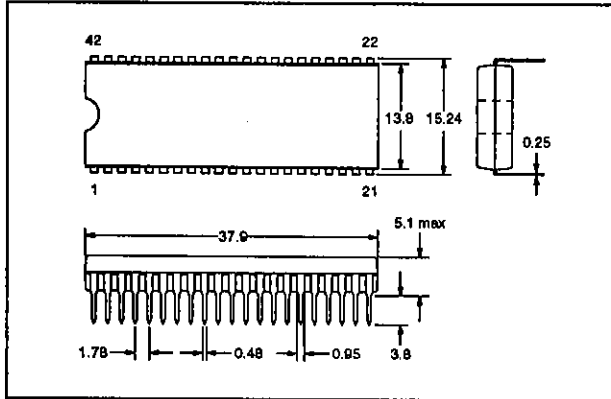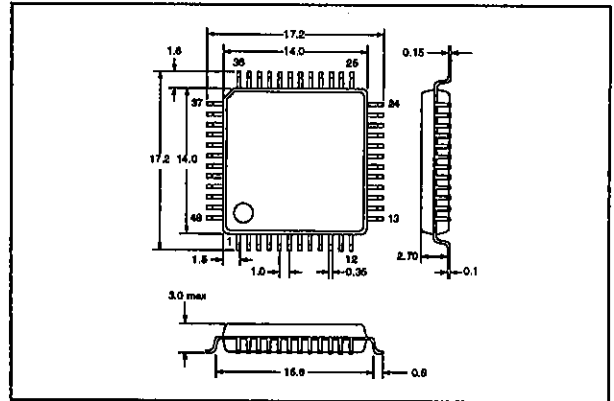* 5 V supply
* 42-pin DIP and 48-pin QIP

PINOUTS

Pin	Name		Name	Pin
1	D0/P00		PE1/TRB/$\overline{OE}$	42
2	D1/P01		PE0/TRA/$\overline{CE}$	41
3	D2/P02		VDD	40
4	D3/P03		PD3/CMP3/$\overline{PGM}$	39
5	D4/P10		PD2/CMP2	38
6	D5/P11		PD1/CMP1	37
7	D6/P12		PD0/CMP0	36
8	D7/P13		PC3/VREF1	35
9	A0/SI0/P20		PC2/VREF0	34
10	A1/SO0/P21		DASEC/PIN1/P63	33
11	A2/$\overline{SCK0}$/P22	LC66P308	$\overline{SCK1}$/P62	32
12	A3/$\overline{INT0}$/P23		SO1/P61	31
13	A4/$\overline{INT1}$/P30		SI1/P60	30
14	A5/POUT0/P31		$\overline{INT2}$/P53	29
15	A6/POUT1/P32		A13/P52	28
16	$\overline{HOLD}$/P33		A12/P51	27
17	A7/P40		A11/P50	26
18	A8/P41		A10/P43	25
19	VPP/TEST		A9/P42	24
20	VSS		$\overline{RES}$	23
21	OSC1		OSC2	22

48-pin QIP pinout for LC66P308.

SANYO Electric Co., Ltd. Semiconductor Business Headquarters
TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110 JAPAN

6082JN(US) / 8089TA №3122-1/17

PACKAGE DIMENSIONS

Unit: mm

3025B-DIP42S

3156-QIP48E

BLOCK DIAGRAM
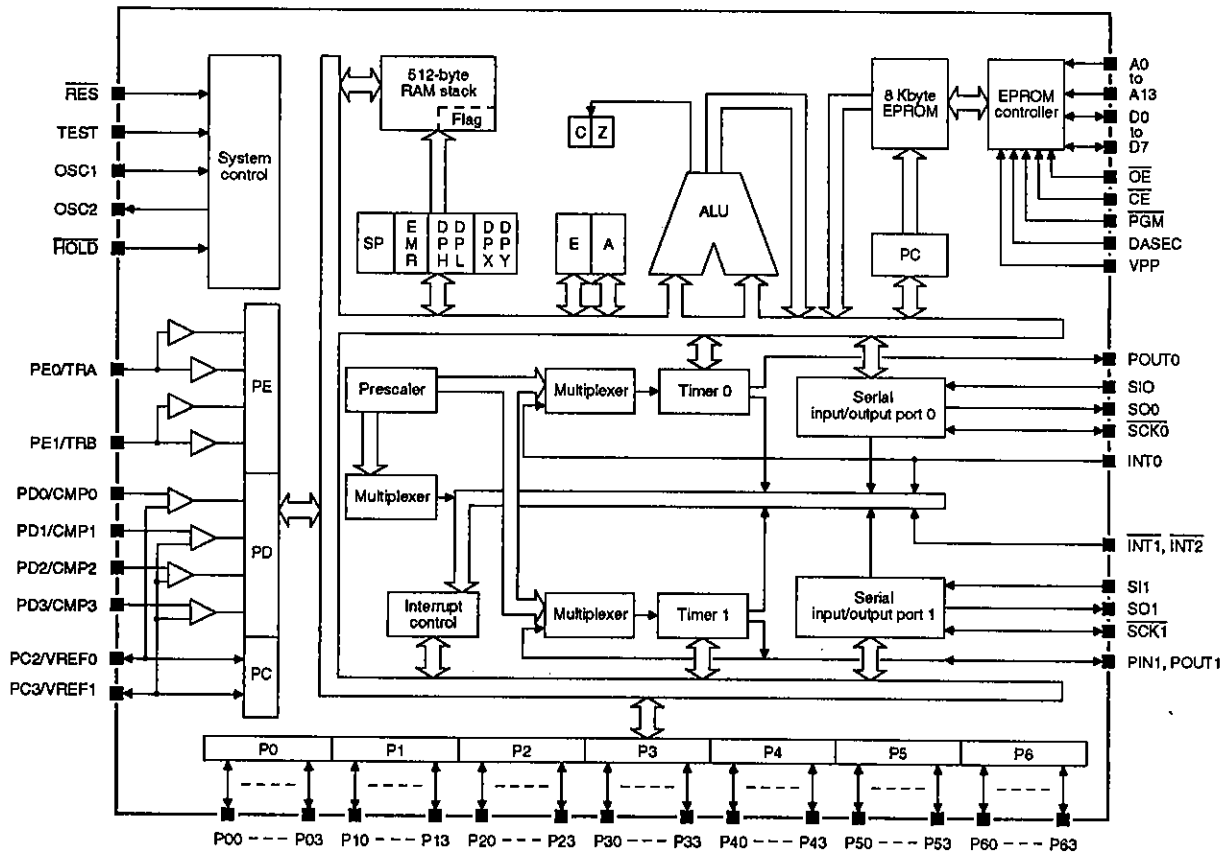
PIN DESCRIPTION

Number		Name	Description
DIP42S	QIP48E		
1	44	D0/P00	Multiplexed 4-bit input/output port P0 (P00 to P03) and PROM data bus lines (D0 to D3)
2	45	D1/P01	
3	46	D2/P02	
4	47	D3/P03	
5	48	D4/P10	Multiplexed 4-bit input/output port P1 (P10 to P13) and PROM data bus lines (D4 to D7)
6	1	D5/P11	
7	2	D6/P12	
8	3	D7/P13	
9	4	A0/SI0/P20	Multiplexed 4-bit input/output port P2 (P20 to P23), serial input 0 (SI0), serial output 0 (SO0), serial clock 0 ($\overline{SCK0}$), interrupt request 0 (INT0) and PROM address bus lines (A0 to A3)
10	5	A1/SO0/P21	
11	7	A2/$\overline{SCK0}$/P22	
12	8	A3/INT0/P23	
13	9	A4/$\overline{INT1}$/P30	Multiplexed 3-bit input/output port P3 (P30 to P32), interrupt request 1 ($\overline{INT1}$), timer outputs (POUT0 and POUT1) and address bus lines (A4 to A6) multiplexed single-bit input port (P33) and hold-mode control input ($\overline{HOLD}$)
14	10	A5/POUT0/P31	
15	11	A6/POUT1/P32	
16	12	$\overline{HOLD}$/P33	
17	13	A7/P40	Multiplexed 4-bit input/output port P4 (P40 to P43) and PROM address bus lines (A7 to A10)
18	14	A8/P41	
24	22	A9/P42	
25	23	A10/P43	
19	15	VPP/TEST	CPU test input
20	16	VSS	Ground
21	17	OSC1	External oscillator connections
22	20	OSC2	
23	21	$\overline{RES}$	Reset input
26	24	A11/P50	Multiplexed 4-bit input/output port P5 (P50 to P53), interrupt request 2 ($\overline{INT2}$) and PROM address bus lines (A11 to A13)
27	25	A12/P51	
28	26	A13/P52	
29	27	$\overline{INT2}$/P53	
30	28	SI1/P60	Multiplexed 4-bit input/output port P6 (P60 to P63), serial input 1 (SI1), serial output 1 (SO1), serial clock 1 ($\overline{SCK1}$), event counter input (PIN1) and PROM data security control input (DASEC)
31	29	SO1/P61	
32	31	$\overline{SCK1}$/P62	
33	32	DASEC/PIN1/P63	
34	33	PC2/VREF0	Multiplexed 2-bit input/output port PC (PC2 and PC3), CMP0 reference voltage input (VREF0) and CMP1 to CMP3 reference voltage input (VREF1)
35	34	PC3/VREF1	

Number		Name	Description
DIP42S	QIP48E		
36	35	PD0/CMP0	Multiplexed 4-bit input port PD (PD0 to PD3), PROM program control input ($\overline{PGM}$) and comparator inputs (CMP0 to CMP3)
37	36	PD1/CMP1	
38	37	PD2/CMP2	
39	38	PD3/CMP3/$\overline{PGM}$	
40	39	VDD	5 V supply
41	40	PE0/TRA/$\overline{CE}$	Multiplexed 2-bit input port PE (PE0 and PE1), 2-bit three-level input port (TRA and TRB), PROM chip enable ($\overline{CE}$) and output enable ($\overline{OE}$)
42	41	PE1/TRB/$\overline{OE}$	
–	6, 18, 19, 30, 42, 43	NC	No connection

SPECIFICATIONS

Absolute Maximum Ratings

Parameter	Symbol	Rating	Unit
Supply voltage range	V_{DD}	−0.3 to 7.0	V
Ports P2 to P6 (excluding P33) input voltage range. See note 1.	V_{I1}	−0.3 to 15.0	V
Input voltage range for all inputs. See note 2.	V_{I2}	−0.3 to V_{DD} + 0.3	V
Ports P2 to P6 (excluding P33) output voltage range. See note 1.	V_{O1}	−0.3 to 15.0	V
Output voltage range for all outputs. See note 2.	V_{O2}	−0.3 to V_{DD} + 0.3	V
Ports P0, P1, P4 and P5 output source current	$-I_{OP1}$	2	mA
Ports P2, P3 (excluding P33), P6 and PC output source current	$-I_{OP2}$	4	mA
Ports P0 to P6 (excluding P33) and PC output sink current	I_{ON}	20	mA
Ports P0 to P3 (excluding P33), P40 and P41 total sink current	ΣI_{ON1}	75	mA
Ports P42, P43, P5, P6 and PC total sink current	ΣI_{ON2}	75	mA
Ports P0 to P3 (excluding P33), P40 and P41 total source current	$-\Sigma I_{OP1}$	25	mA
Ports P42, P43, P5, P6 and PC total source current	$-\Sigma I_{OP2}$	25	mA
Power dissipation (DIP42S)	P_{D1}	600	mW
Power dissipation (QIP48E). See note 3.	P_{D2}	430	mW
Operating temperature range	T_{opr}	−30 to 70	°C
Storage temperature range	T_{stg}	−55 to 125	°C

Notes

1. Open-drain output configuration option
2. All output configuration options
3. Heat-soak the QIP package before mounting. Do not immerse the package in the solder dip tank when mounting the QIP on the substrate, and avoid prolonged contact with the solder.

Recommended Operating Conditions

$T_a = 25$ °C, $V_{SS} = 0$ V

Parameter	Symbol	Rating	Unit
Supply voltage	V_{DD}	5	V
Supply voltage range	V_{DD}	4.5 to 5.5	V
Hold-mode supply voltage range for data retention	V_{DD}	1.8 to 5.5	V

Electrical Characteristics

$V_{DD} = 4.5$ to 5.5 V, $V_{SS} = 0$ V, $T_a = -30$ to 70 °C unless otherwise noted

Parameter	Symbol	Condition	Rating			Unit
			min	typ	max	
Reset-mode supply current	I_{DD}	4 MHz ceramic resonator	–	4.5	8.0	mA
		4 MHz external clock	–	6.5	11.0	mA
		RC oscillator	–	4	8	mA
Halt-mode supply current	I_{DDHT}	4 MHz ceramic resonator	–	3.0	5.0	mA
		4 MHz external clock	–	3.5	6.0	mA
		RC oscillator	–	3.0	5.0	mA
Hold-mode supply current	I_{DDHD}	$V_{DD} = 1.8$ to 5.5 V	–	0.01	10.0	μA
Ports P2, P3 (excluding P33), P5 and P6, $\overline{RES}$ and OSC1 LOW-level input voltage	V_{IL1}	Output n-channel transistor OFF. See note 1.	V_{SS}	–	$0.25V_{DD}$	V
$\overline{HOLD}$/P33 LOW-level input voltage	V_{IL2}	$V_{DD} = 1.8$ to 5.5 V	V_{SS}	–	$0.25V_{DD}$	V
Ports P0, P1, P4, PC, PD and PE, and TEST LOW-level input voltage	V_{IL3}	Output n-channel transistor OFF. See note 1.	V_{SS}	–	$0.3V_{DD}$	V
Port PE LOW-level input voltage	V_{IL4}	Ternary input mode.	V_{SS}	–	$0.2V_{DD}$	V
Port PE MID-level input voltage	V_{IM}	Ternary input mode.	$0.4V_{DD}$	–	$0.6V_{DD}$	V
Ports P2 to P6 (excluding P33) HIGH-level input voltage	V_{IH1}	Output n-channel transistor OFF. See note 2.	$0.75V_{DD}$	–	13.5	V
$\overline{HOLD}$/P33, $\overline{RES}$ and OSC1 HIGH-level input voltage	V_{IH2}	Output n-channel transistor OFF	$0.75V_{DD}$	–	V_{DD}	V
Ports P0, P1, PC, PD and PE HIGH-level input voltage	V_{IH3}	Output n-channel transistor OFF. See note 1.	$0.7V_{DD}$	–	V_{DD}	V
Port PE HIGH-level input voltage	V_{IH4}	Ternary input mode.	$0.8V_{DD}$	–	V_{DD}	V
Ports P0 to P6 (excluding P33) and PC LOW-level output voltage	V_{OL}	$I_{OL} = 1.6$ mA	–	–	0.4	V
		$I_{OL} = 10$ mA	–	–	1.5	
Ports P2, P3 (excluding P33), P6 and PC HIGH-level output voltage	V_{OH1}	$I_{OH} = -1$ mA. See note 3.	$V_{DD} - 1.0$	–	–	V
		$I_{OH} = -0.1$ mA. See note 3.	$V_{DD} - 0.5$	–	–	
Ports P0, P1, P4 and P5 HIGH-level output voltage	V_{OH2}	$V_{DD} = 4.5$ V, $I_{OH} = -0.2$ mA. See note 4.	2.4	–	–	V
		$I_{OH} = -0.13$ mA. See note 4.	$V_{DD} - 1.35$	–	–	

Parameter	Symbol	Condition	Rating			Unit
			min	typ	max	
Ports PC and PD in-phase, comparator input voltage	V_{CMM}		1.0	–	V_{DD} - 1.5	V
Port PD comparator offset voltage	V_{OFF}	V_I = 1.0 to V_{DD} − 1.5 V	–	±50	±300	mV
Ports P2, P3, P5 and P6, and $\overline{RES}$ and OSC1 Schmitt-trigger LOW-level threshold voltage	V_{tL}		$0.25V_{DD}$	–	$0.5V_{DD}$	V
Ports P2, P3, P5, and P6, and $\overline{RES}$ and OSC1 Schmitt-trigger HIGH-level threshold voltage	V_{tH}		$0.5V_{DD}$	–	$0.75V_{DD}$	V
Ports P2, P3, P5 and P6, $\overline{RES}$ and OSC1 Schmitt-trigger hysteresis voltage	V_{HYS}		–	$0.1V_{DD}$	–	V
LOW-level input current for all inputs	I_{IL}	V_I = V_{SS}, output n-channel transistor OFF. See note 2.	−1	–	–	μA
Ports P2 to P6 (excluding P33) HIGH-level input current	I_{IH1}	V_I = 13.5 V, output n-channel transistor OFF. See note 2.	–	–	5	μA
Ports P0, P1 and P33, and $\overline{RES}$ and OSC1 HIGH-level input current	I_{IH2}	V_I = V_{DD}, output n-channel transistor OFF. See note 1.	–	–	1	μA
Ports PC2, PC3, PD and PE HIGH-level input current	I_{IH3}	V_I = V_{DD}, output n-channel transistor OFF. See note 1.	–	–	1	μA
Ports P2 to P6 output leakage current	I_{OFF1}	V_I = 13.5 V. See note 2.	–	–	5	μA
Ports P0, P1 and PC output leakage current	I_{OFF2}	V_I = V_{DD}. See note 2.	–	–	1	μA
Ports P0, P1, P4 and P5 output current with pull-up option	I_{PO}	V_I = V_{SS}, V_{DD} = 5.5 V. See note 4.	−1.6	–	–	mA
Ceramic resonator input frequency	f_{CF}	4 MHz resonator	–	4	–	MHz
Ceramic resonator input stabilization time	t_{CFS}	4 MHz resonator	–	–	10	ms
RC oscillator input frequency	f_{RC}	R = 2.2 kΩ ±1%, C = 100 pF ±5%	2	3	4	MHz
External RC oscillator capacitance	C_{ext}		–	100	–	pF
External RC oscillator resistance	R_{ext}		–	2.2	–	kΩ

Notes

1. Ports with CMOS output configuration option cannot be used as input ports.
2. Open-drain output configuration option
3. CMOS output configuration option
4. Pull-up output configuration option

## Timing Characteristics

Serial input/output timing
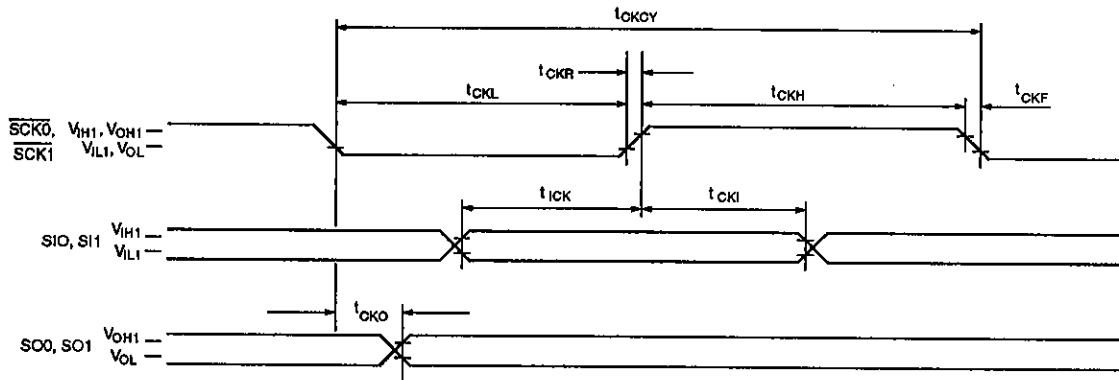
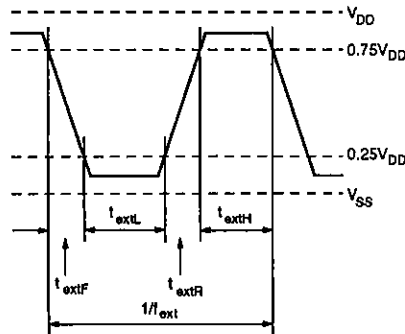V_{DD} = 4.5 to 5.5 V, V_{SS} = 0 V, T_a = −30 to 70 °C

Parameter	Symbol	Rating			Unit
		min	typ	max	
Instruction cycle time	t_{CYC}	0.92	–	10	µs
$\overline{SCK0}$ and $\overline{SCK1}$ serial clock input cycle time	t_{CKCY}	0.9	–	–	µs
$\overline{SCK0}$ and $\overline{SCK1}$ serial clock output cycle time	t_{OCY}	$2t_{CYC}$	–	–	µs
$\overline{SCK0}$ and $\overline{SCK1}$ serial clock input pulsewidth	t_{CKL}	0.4	–	–	µs
$\overline{SCK0}$ and $\overline{SCK1}$ serial clock output pulsewidth	t_{CKH}	t_{CYC}	–	–	µs
$\overline{SCK0}$ and $\overline{SCK1}$ serial clock output rise time	t_{CKR}	–	–	0.1	µs
$\overline{SCK0}$ and $\overline{SCK1}$ serial clock output fall time	t_{CKF}	–	–	0.1	µs
SI0 and SI1 serial data setup time	t_{ICK}	0.3	–	–	µs
SI0 and SI1 serial data hold time	t_{CKI}	0.3	–	–	µs
SO0 and SO1 serial data output delay	t_{CKO}	–	–	0.3	µs

Note

Each test input and output has an RC load as shown in the following figure.

V_{DD}

Test point

1 kΩ

50 pF
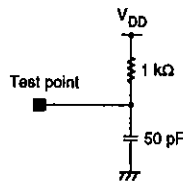
External clock timing

V_{DD} = 4.5 to 5.5 V, V_{SS} = 0 V, T_a = −30 to 70 ℃

Parameter	Symbol	Rating			Unit
		min	typ	max	
OSC1 external clock input frequency	f_{ext}	0.4	–	4.35	MHz
OSC1 external clock LOW-level input pulsewidth	t_{extL}	70	–	–	ns
OSC1 external clock HIGH-level input pulsewidth	t_{extH}	70	–	–	ns
OSC1 external clock input rise time	t_{extR}	–	–	30	ns
OSC1 external clock input fall time	t_{extF}	–	–	30	ns

Interrupt and reset timing
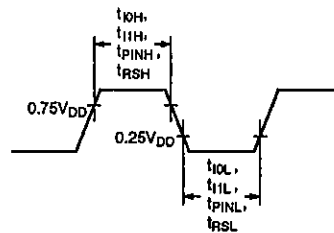
V_{DD} = 4.5 to 5.5 V, V_{SS} = 0 V, T_a = −30 to 70 ℃

Parameter	Symbol	Rating			Unit
		min	typ	max	
INT0 LOW-level pulsewidth	t_{I0L}	$2t_{CYC}$	–	–	µs
INT0 HIGH-level pulsewidth	t_{I0H}	$2t_{CYC}$	–	–	µs
INT1 and INT2 LOW-level pulsewidth	t_{I1L}	$2t_{CYC}$	–	–	µs
INT1 and INT2 HIGH-level pulsewidth	t_{I1H}	$2t_{CYC}$	–	–	µs
PIN1 LOW-level input pulsewidth	t_{PINL}	$2t_{CYC}$	–	–	µs
PIN1 HIGH-level input pulsewidth	t_{PINH}	$2t_{CYC}$	–	–	µs
RES LOW-level input pulsewidth	t_{RSL}	$3t_{CYC}$	–	–	µs
RES HIGH-level input pulsewidth	t_{RSH}	$3t_{CYC}$	–	–	µs

Comparator timing
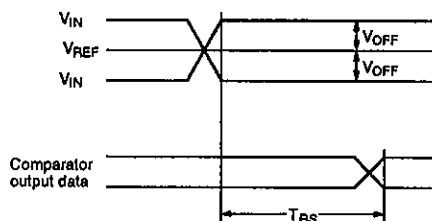
V_{DD} = 4.5 to 5.5 V, V_{SS} = 0 V, T_a = −30 to 70 °C

Parameter	Symbol	Condition	Rating			Unit
			min	typ	max	
Port PD comparator response time	t_{RS}		–	–	30	μs

INPUT AND OUTPUT FUNCTIONS

The LC66P308 has many multiplexed pins whose function is controlled by software. The function of each of these pins is shown in the following table.

Name	Function
D0/P00	Ports P00 to P03 can be addressed as either a 4-bit port or four, single-bit ports. They function as data bus lines when memory is addressed. They also have halt-mode control functions. Level after reset is set by user option.
D1/P01	
D2/P02	
D3/P03	
D4/P10	Ports P10 to P13 can be addressed as either a 4-bit port or four, single-bit ports. They function as data bus lines when memory is addressed. Level after reset is set by user option.
D5/P11	
D6/P12	
D7/P13	
A0/SI0/P20	Ports P20 to P23 can be addressed as either a 4-bit port or four, single-bit ports. They function as address bus inputs when memory is addressed. Port P20 also functions as a serial data input, P21 as a serial data output, P22 as a serial data clock and P23 as an interrupt request, pulsewidth measurement and event counter input using timer 0.
A1/SO0/P21	
A2/SCK0/P22	
A3/INT0/P23	
A4/INT1/P30	Ports P30 to P32 can be addressed as either a 3-bit port, a 4-bit port with P33 or three, single-bit ports. They function as address bus inputs when memory is addressed. Port P30 also functions as an interrupt request input, P31 as a square-wave output from timer 0 and P32 as a square-wave output from timer 1 and a PWM output.
A5/POUT0/P31	
A6/POUT1/P32	
HOLD/P33	Port P33 can be addressed as either a 4-bit port with P30 to P32 or a single-bit port. It functions as the hold-mode control input when P33 is LOW and the HOLD instruction is executed. The CPU restarts when P33 goes HIGH again. Reset signals are ignored whenever HOLD/P33 is LOW, including when not in hold mode.
A7/P40	Ports P40 to P43 can be addressed as either a 4-bit port, four, single-bit ports or an 8-bit port with P50 to P53. They function as address bus inputs when memory is addressed.
A8/P41	
A9/P42	
A10/P43	

Name	Function
A11/P50	Ports P50 to P53 can be addressed as either a 4-bit port, four, single-bit ports or an 8-bit port with P40 to P43. Ports P50 to P52 function as address bus inputs when memory is addressed. Port P53 also functions as an interrupt request input.
A12/P51	
A13/P52	
INT2/P53	
SI1/P60	Ports P60 to P63 can be addressed as either a 4-bit port or four, single-bit ports. Port P60 also functions as a serial data input, P61 as a serial data output, P62 as a serial data clock and P63 as a data security control input and timer 1 event counter input.
SO1/P61	
SCK1/P62	
DASEC/PIN1/P63	
PC2/VREF0	Ports PC2 and PC3 can be addressed as either a 2-bit port or two, single-bit ports. In addition, Port PC2 also functions as the PD0 reference voltage input, and PC3 as the PD1 to PD3 reference voltage input.
PC3/VREF1	
PD0/CMP0	Ports PD0 to PD3 can be addressed as either a 4-bit port or four, single-bit ports. They also function as comparator inputs. In addition, port PD3 also functions as the memory program control input.
PD1/CMP1	
PD2/CMP2	
PD3/CMP3/PGM	
PE0/TRA/CE	Ports PE0 to PE1 can be addressed as either a 2-bit port or two, single-bit ports. They function as chip enable and write enable, respectively, when memory is addressed. They also function as three-level inputs.
PE1/TRB/OE	
OSC1	OSC1 and OSC2 function as the external ceramic resonator or RC oscillator connections. When an external clock is used, OSC2 is left open.
OSC2	
RES	When RES goes LOW while HOLD/P33 is HIGH, the CPU is reset.
VPP/TEST	CPU test input. Normally connected to ground

USER OPTIONS

Oscillator Options

There are three user options for the oscillator—an external clock, an RC oscillator and a ceramic resonator. The internal circuits of OSC1 and OSC2 for the external clock, RC oscillator and ceramic resonator options are shown in figures 1, 2 and 3, respectively. Note the Schmitt-trigger inputs for both the external clock and RC oscillator options.

Figure 3. Ceramic resonator option
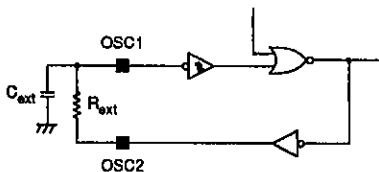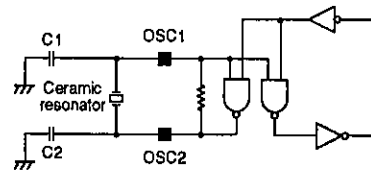

Figure 1. External clock option

Figure 2. RC oscillator option

Output Options

There are two user options for the output configuration of each port—n-channel open drain and p-channel, active pull-up, shown in figures 4 and 5, respectively. Ports P2, P3, P5 and P6 have Schmitt-trigger inputs in both output configurations.
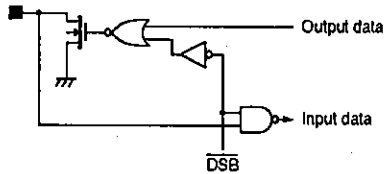

Figure 4. N-channel open-drain option

The p-channel pull-up option for ports P0, P1, P4 and P5 results in an n-channel sink transistor with a p-channel, active pull-up transistor configuration, and for ports P2, P3, P6 and PC, a CMOS configuration.
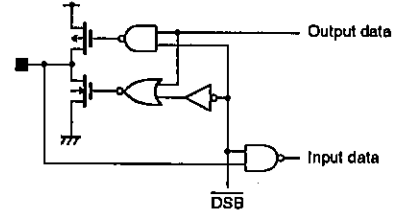
Figure 5. P-channel pull-up option

The n-channel open-drain outputs for ports P2 to P6 have a withstand voltage greater than 15 V.

Output Level After Reset Option

The output level of ports P0 and P1 after a CPU reset is user selectable.

Watchdog Timer Option

A watchdog timer is available to prevent program runaway.

PROM SPECIFICATION

Specifying Programs and Options

The user-addressable memory is 0000H to 2007H. Addresses 0000H to 1FFFH are for user programs, and addresses 2000H to 2007H, for option specification. Addresses 2008H and above can neither be programmed or read. The option specification is coded using the information shown in the following table.

Address	Data bit	Parameter	Option	
			0	1
2000H	D0	Watchdog timer function	No	Yes
	D1	Port P0 level after reset	LOW	HIGH
	D2	Port P1 level after reset	LOW	HIGH
	D3	No function	Set to 0	
	D4	Oscillator	RC oscillator or external clock	Ceramic resonator
	D5 to D7	No function	Set to 0	
2001H	D0	Port P00 output configuration	Open-drain	Pull-up
	D1	Port P01 output configuration		
	D2	Port P02 output configuration		
	D3	Port P03 output configuration		
	D4	Port P10 output configuration	Open-drain	Pull-up
	D5	Port P11 output configuration		
	D6	Port P12 output configuration		
	D7	Port P13 output configuration		

Address	Data bit	Parameter	Option	
			0	1
2002H	D0	Port P20 output configuration	Open-drain	CMOS
	D1	Port P21 output configuration		
	D2	Port P22 output configuration		
	D3	Port P23 output configuration		
	D4	Port P30 output configuration	Open-drain	CMOS
	D5	Port P31 output configuration		
	D6	Port P32 output configuration		
	D7	No function	Set to 0	
2003H	D0	Port P40 output configuration	Open-drain	Pull-up
	D1	Port P41 output configuration		
	D2	Port P42 output configuration		
	D3	Port P43 output configuration		
	D4	Port P50 output configuration	Open-drain	Pull-up
	D5	Port P51 output configuration		
	D6	Port P52 output configuration		
	D7	Port P53 output configuration		
2004H	D0	Port P60 output configuration	Open-drain	CMOS
	D1	Port P61 output configuration		
	D2	Port P62 output configuration		
	D3	Port P63 output configuration		
	D4 to D7	No function	Set to 0	
2005H	D0 to D7	No function	Set to 0	
2006H	D0 to D7	No function	Set to 0	
2007H	D0, D1	No function	Set to 0	
	D2	Port PC2 output configuration	Open-drain	CMOS
	D3	Port PC3 output configuration		
	D4 to D7	No function	Set to 0	

The assembler execute command when specifying programs and options using a Sanyo cross assembler is LC66S.EXE.

PROM Programming

The PROM can be programmed using a special adapter board, W66EP308D/408D for the 42-pin DIP and W66EP308Q/408Q for the 48-pin QIP as shown in the following figure, and a universal EPROM programmer.

LC66P308
(DIP42S)

W66EP308D/408D

DASEC
security
switch

LC66P308
(QIP48E)

W66EP308Q/408Q

DASEC
security
switch

DASEC security switch OFF

ON   OFF

DASEC security switch ON

ON   OFF
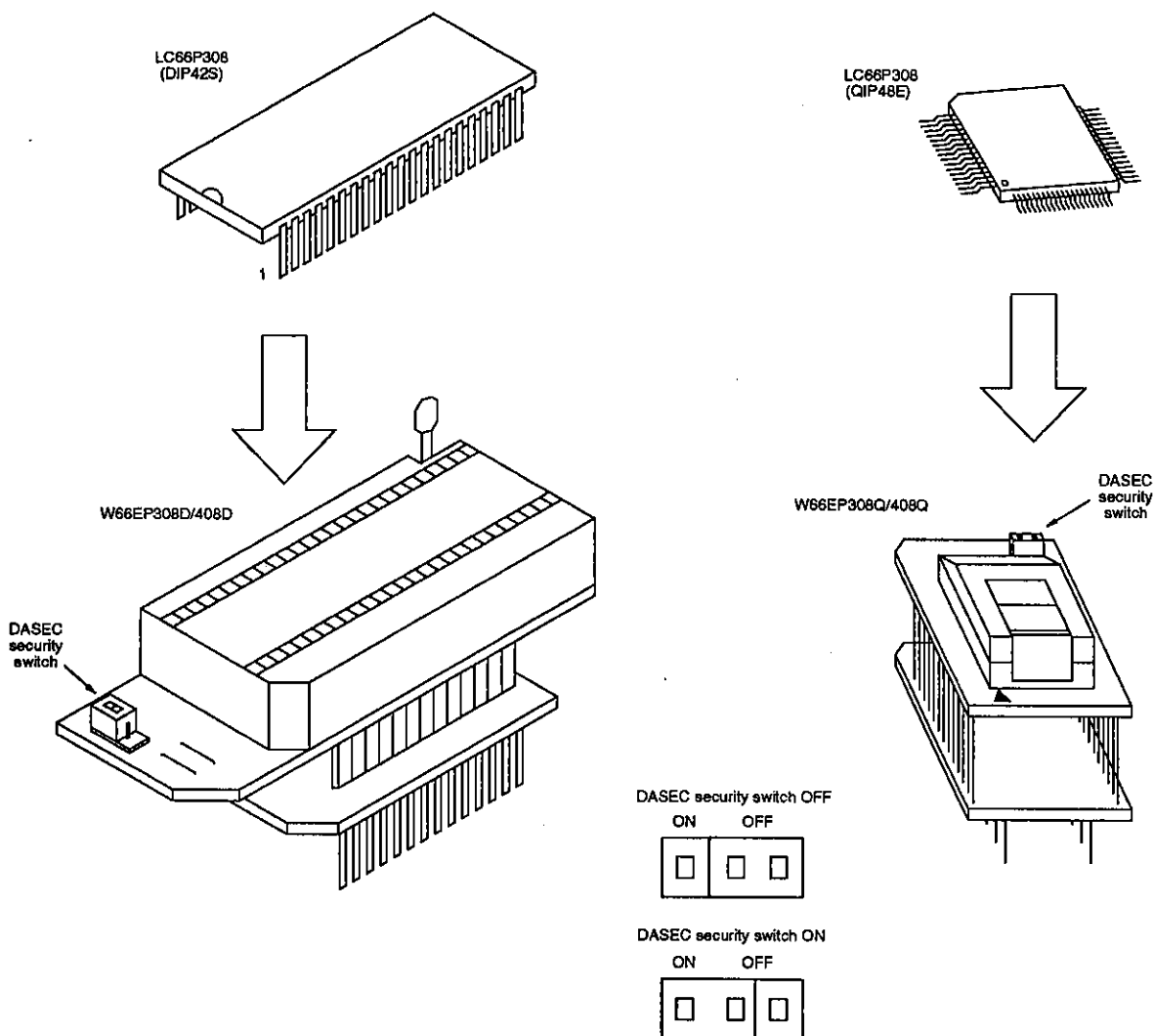
Program the LC66P308 using the M mode of the PV command of the EVA800 or EVA850. The EPROM programmer should be Intel 27128 compatible with V_{PP} = 21 V. The recommended programmers are shown in the following table. Please contact your nearest Sanyo representative if you intend to use an alternative EPROM programmer.

Manufacturer	Model
ADVANTEST	TR4943, R4944A, R4945 or equivalent
Sanyo	EVA850 or EVA800 special-purpose programmers

Notes

1. Intel is a registered trademark of Intel Corporation.
2. ADVANTEST is a registered trademark of ADVANTEST Corporation.

The EPROM programmer adapter incorporates a data security switch. When this switch is ON, data is secure, and when OFF, the data lines are floating and the PROM can be programmed. Note that when the data lines are floating, the EPROM programmer will return an error. This error can be ignored.

APPLICATION NOTES

Reset Timing

The reset signal on $\overline{\text{RES}}$ should be held LOW for a minimum of three instruction cycles after the oscillator has stabilized to ensure correct operation, as shown in the following figure.

VDD _____ 4.5 V

OSC

> 10 ms | > 3 Instruction cycles

$\overline{\text{RES}}$ — V_{IH}

Oscillator stabilization time

8 instruction cycles

Program execution — AD0 — AD1

Port output format — Open drain | Option | Option-specified format

switching period
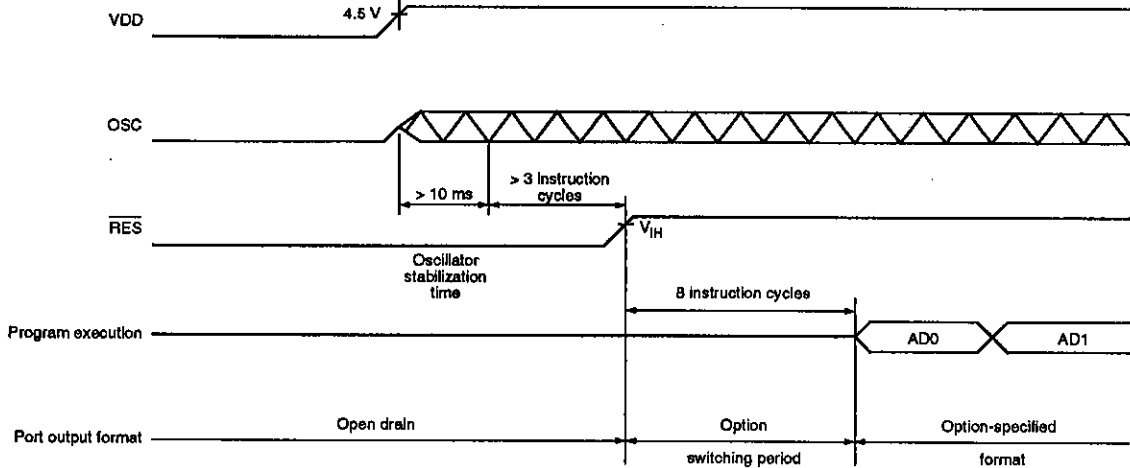
After a reset occurs, all I/O ports are reset to open-drain output configuration with floating outputs, except for ports P0 and P1 which both have an output level after reset option. The output configuration of each port is then set using the specified options during the eight instruction cycles after $\overline{\text{RES}}$ goes HIGH. Program execution then begins from address 0000H.

The LC66E308/P308 can be reset while in hold mode ($\overline{\text{HOLD}}$/P33 is LOW). When $\overline{\text{RES}}$ goes LOW in hold mode, $\overline{\text{HOLD}}$/P33 must go HIGH before $\overline{\text{RES}}$ goes HIGH again.

Ceramic resonator	Capacitance	
	C1	C2
4 MHz Murata CSA-4.00MG	33 pF ±10%	33 pF ±10%
4 MHz Kyocera KBR-4.0MS	33 pF ±10%	33 pF ±10%
4 MHz Murata CST-4.00MG with internal capacitor	N/A	N/A
4 MHz Kyocera KBR-4.0MES with internal capacitor	N/A	N/A

Reference Clock

The external circuit for a ceramic resonator is shown in figure 6, and the recommended resonator and component values, in the following table. The oscillator stabilization characteristics are shown in figure 7.

OSC1   OSC2

Ceramic resonator

C1   C2
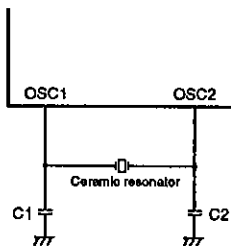
Figure 6. Ceramic resonator

V_{DD} _____ V_{DD} (min)

0 V

OSC

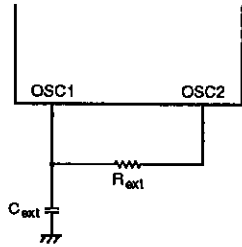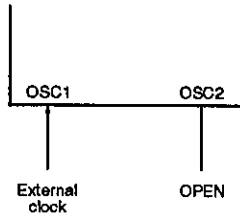t_{CFS} Stable oscillation

Unstable oscillation
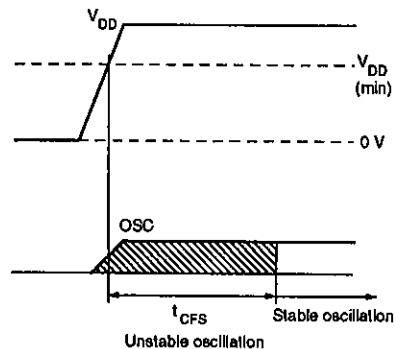
Figure 7. Ceramic resonator stabilization time

The external circuit for an RC oscillator is shown in the following figure.

The external clock input connection is OSC1. The remaining oscillator connection, OSC2, should be left open as shown in the following figure.


The RC oscillator frequency is determined by the external resistor and capacitor and has only been specified for $R_{ext} = 2.2$ kΩ and $C_{ext} = 100$ pF. The frequency for other values of R_{ext} and C_{ext} can be determined from the graph in the following figure.
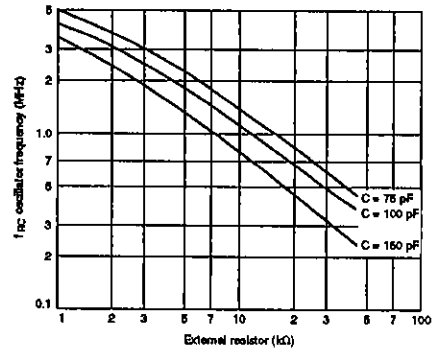
Preparation Procedure

The preparation procedures shown in the following figure for DIP and QIP packages should always be followed prior to mounting the packages on the sub-strate. Note that the QIP package should be heat-soaked for 24 hours at 125 °C immediately prior to mounting.
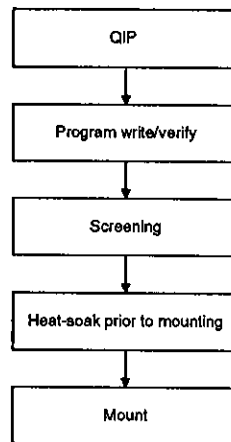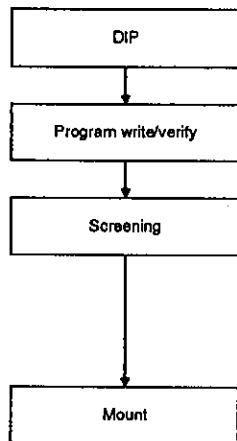
Screening procedure

The construction of the microcontroller with a blank built-in PROM makes it impossible for Sanyo to completely factory-test it before shipping. To prove reliability of the programmed devices, the screening procedure shown in the following figure should always be followed.
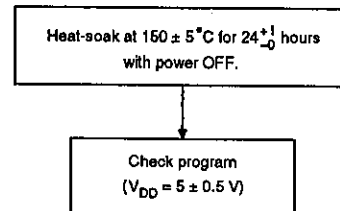
Note that it is not possible to perform a write test on the blank PROM. 100% yield, therefore, cannot be guaranteed.

ORDERING INFORMATION

When ordering identical mask ROM and PROM devices simultaneously, provide an EPROM containing the target memory contents together with separate order forms for each of the mask ROM and PROM versions.

When ordering a PROM device, provide an EPROM containing the target memory contents together with an order form.

When ordering either an LC66354A 4 Kbyte or LC66356A 6 Kbyte mask ROM device, insert a jump command, or any similar command, to avoid executing an address beyond the range of the target device. In addition, write a 0 into all locations above 2007H.

A comparison of the LC66P308 characteristics with those of the LC663XX mask ROM devices is shown in the following table.

Parameter	Symbol	Condition	LC66P308	LC663XX series		Unit
				LC6630X series	LC66354A/6A/8A	
Supply voltage range	V_{DD}	t_{CYC} = 0.92 to 10 μs	4.5 to 5.5	4.0 to 6.0	–	V
		t_{CYC} = 3.92 to 10 μs	–	–	2.2 to 5.5	
		t_{CYC} = 1.96 to 10 μs	–	–	3.0 to 5.5	
Maximum halt-mode supply current	I_{DDHT}	4 MHz ceramic resonator	5.0	2.5	2.5	mA
		4 MHz external clock	6.0	3.5	3.5	
		3 MHz (typ) RC oscillator	5.0	2.5	–	
Hold-mode release hardware delay	N_{HOLD}		65,536	65,536	16,384	Cycles
Hold-mode release time	t_{HOLD}	f_{OSC} = 4 MHz (t_{CYC} = 1 μs)	≈64	≈64	–	ms
		f_{OSC} = 2 MHz (t_{CYC} = 2 μs)	–	–	≈32	
		f_{OSC} = 1 MHz (t_{CYC} = 4 μs)	–	–	≈64	
External RC oscillator capacitance	C_{ext}		100	100	–	pF
External RC oscillator resistance	R_{ext}		2.2	2.7	–	kΩ
Timer 0 contents after reset or hold-mode release			FF0	FF0	FFC	Hex
Port output configuration after reset			See note.	Specified by user option	Specified by user option	

Note

Ports P2 to P6 and PC are open-drain and floating. Ports P0 and P1 have pull-up resistances and are HIGH or LOW.

A breakdown of the LC66 series devices, which includes the LC66308 and LC663XX devices, is shown in the following table.

Device	Pins	ROM capacity	RAM capacity	Package type
LC66304A/306A/308A	42/48	4/6/8 Kbyte ROM	512 bytes	DIP42S or QIP48E
LC66354A/356A/358A	42/48	4/6/8 Kbyte ROM	512 bytes	DIP42S or QIP48E
LC66354SV/356SV/358SV	44	4/6/8 Kbyte ROM	512 bytes	QIP44M
LC66E308	42/48	8 Kbyte EPROM	512 bytes	DIC42S or QIC48
LC66P308	42/48	8 Kbyte PROM	512 bytes	DIP42S or QIP48E
LC66404A/406A/408A	42/48	4/6/8 Kbyte ROM	512 bytes	DIP42S or QIP48E
LC66E408	42/48	8 Kbyte EPROM	512 bytes	DIC42S or QIC48
LC66P408	42/48	8 Kbyte PROM	512 bytes	DIP42S or QIP48E
LC66506B/508B/512B/516B	64	6/8/12/16 Kbyte ROM	512 bytes	DIP64S or QIP64A
LC66556A/558A/562A/566A	64	6/8/12/16 Kbyte ROM	512 bytes	DIP64S or QIP64E
LC66E516	64	16 Kbyte EPROM	512 bytes	DIC64S or QIC64
LC66P516	64	16 Kbyte PROM	512 bytes	DIP64S or QIP64E

Note

∇ = under development

Sanyo ROM Services

Sanyo offers various services at nominal charges. These include ROM writing, ROM reading, and package stamping and screening. Contact your local Sanyo representative for further information.